



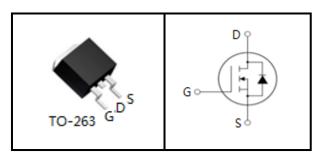
60V N-Channel DTMOS

FEATURES

- Trench Power DTMOS Technology
- Low R_{DS(ON)}
- Low Gate Charge
- Optimized for fast-switching Applications

APPLICATIONS

- Synchronous Rectification in DC/DC and AC/DC Converters
- Isolated DC/DC Converters in Telecom and Industrial





Device Marking and Package Information				
Device	Package	Marking		
TSB15N06A	TO-263	15N06A		

Absolute Maximum Ratings $T_c = 25^{\circ}C$, unless otherwise noted						
Parameter		Symbol	Value	Unit		
Drain-Source Voltage (V _{GS} = 0V)		V _{DSS}	60	V		
Continuous Drain Current (Package Limited)		I _D	180	А		
Pulsed Drain Current ((note1)	I _{DM}	720	А		
Gate-Source Voltage		V _{GSS}	±20	V		
Single Pulse Avalanche Energy (note2)	E _{AS}	609	mJ		
Avalanche Current (note1)	I _{AS}	28	А		
Power Dissipation ($T_c = 25^{\circ}C$)		P _D	208	W		
Operating Junction and Storage Temperature Range		T _J , T _{stg}	-55~+150	°C		

Thermal Resistance					
Parameter	Symbol	Value	Unit		
Thermal Resistance, Junction-to-Case	R _{thJC}	0.6	00.00/		
Thermal Resistance, Junction-to-Ambient	R _{thJA}	60	∘C/W		

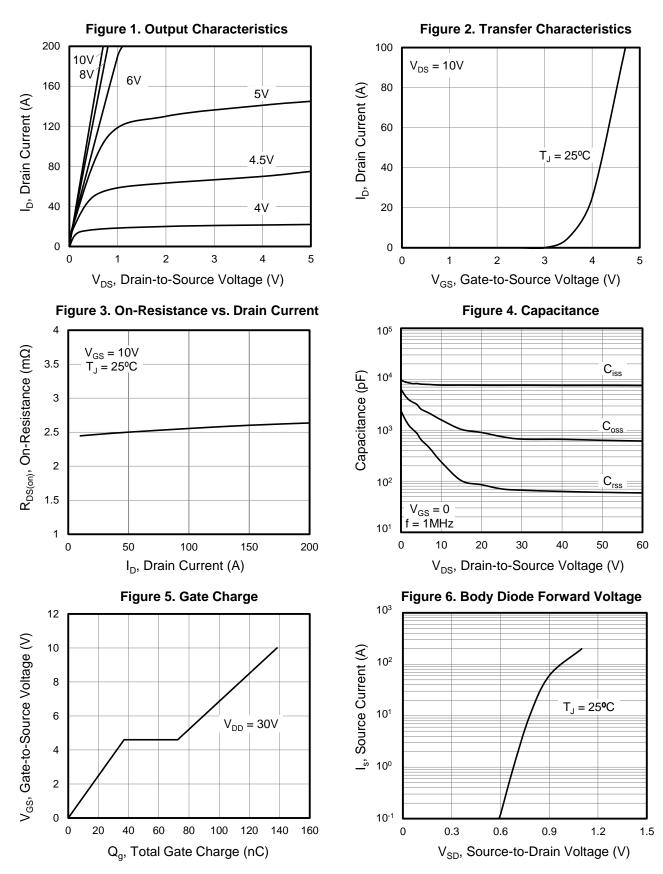


Specifications $T_J = 25^{\circ}C$, un				Value			
Parameter	Symbol	Test Conditions	Value			Unit	
			Min.	Тур.	Max.		
Static							
Drain-Source Breakdown Voltage	$V_{(BR)DSS}$	$V_{GS} = 0V, I_D = 250\mu A$	60			V	
Zero Gate Voltage Drain Current	I _{DSS}	$V_{DS} = 60V, V_{GS} = 0V, T_{J} = 25^{\circ}C$			1	μA	
		$V_{DS} = 60V, V_{GS} = 0V, T_{J} = 150^{\circ}C$			100		
Gate-Source Leakage	I _{GSS}	V_{GS} = $\pm 20V$			±100	nA	
Gate-Source Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$	2		4	V	
Drain-Source On-Resistance (Note3)	R _{DS(on)}	$V_{GS} = 10V, I_{D} = 50A$		2.5	3	mΩ	
Forward Transconductance (Note3)	g _{fs}	V _{DS} = 10V, I _D = 50A		140		S	
Dynamic							
Input Capacitance	C _{iss}			7710		pF	
Output Capacitance	C _{oss}	$V_{GS} = 0V,$ $V_{DS} = 30V,$		667			
Reverse Transfer Capacitance	C _{rss}	f = 1.0MHz		66			
Total Gate Charge	Q _g			138		nC	
Gate-Source Charge	Q _{gs}	$V_{DD} = 30V, I_{D} = 50A, V_{GS} = 10V$		37			
Gate-Drain Charge	Q_{gd}			35.5			
Turn-on Delay Time	t _{d(on)}			35		ns	
Turn-on Rise Time	t _r	V _{DD} = 30V, I _D = 50A,		22			
Turn-off Delay Time	t _{d(off)}	$R_{\rm G} = 25\Omega$		105			
Turn-off Fall Time	t _f			45			
Drain-Source Body Diode Characteris	stics			•			
Continuous Body Diode Current	I _S	T 0700			50	- A	
Pulsed Diode Forward Current	I _{SM}	T _C = 25°C			150		
Body Diode Voltage	V _{SD}	T _J = 25°C, I _{SD} = 50A, V _{GS} = 0V		0.9	1.2	V	
Reverse Recovery Time	t _{rr}	I _F = 50A,		50		ns	
Reverse Recovery Charge	Q _{rr}	di _F /dt = 500A/µs		110		nC	

Notes

- 1. Repetitive Rating: Pulse Width limited by maximum junction temperature
- 2. I_{AS} = 28A, V_{DD} = 50V, R_{G} = 25 Ω , Starting T_{J} = 25 $^{\circ}$ C
- 3. Pulse Test: Pulse Width \leq 300µs, Duty Cycle \leq 1%

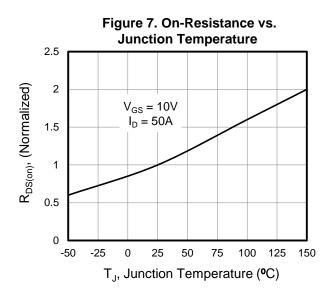
Typical Characteristics $T_J = 25^{\circ}C$, unless otherwise noted



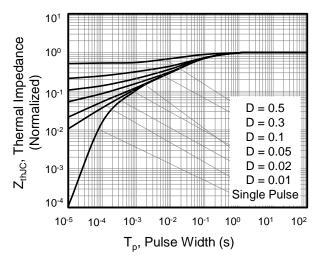
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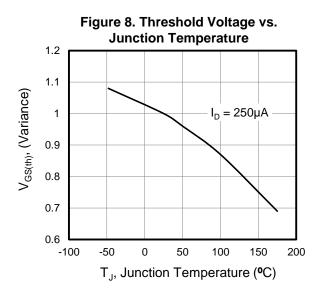
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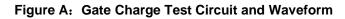
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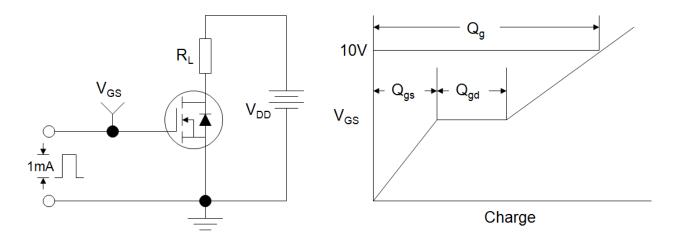


Figure B: Resistive Switching Test Circuit and Waveform

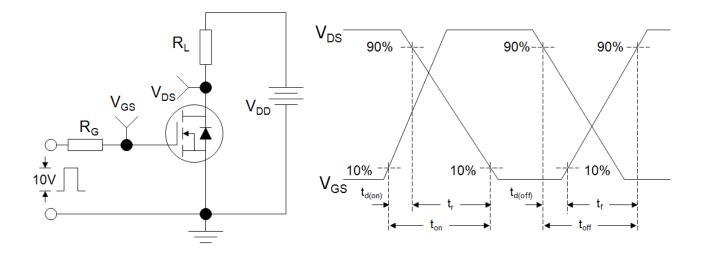
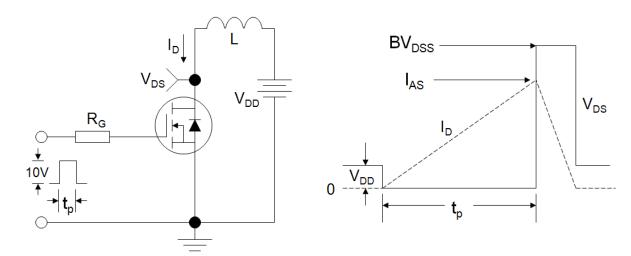
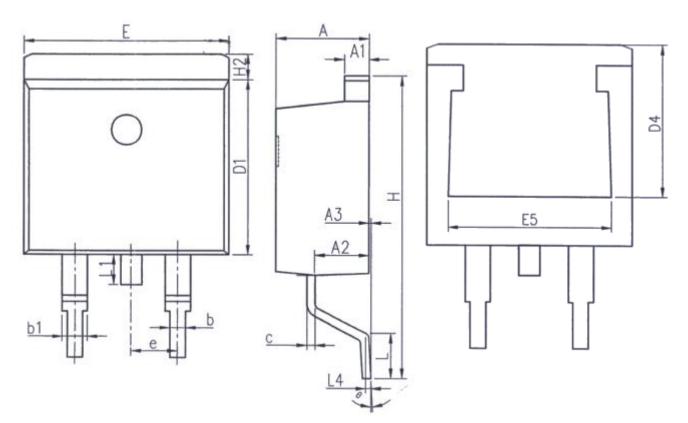


Figure C: Unclamped Inductive Switching Test Circuit and Waveform



TO-263



Unit: mm			Unit: mm		
Symbol	Min.	Max.	Symbol	Min.	Max.
Α	4. 37	4. 77	E	9.86	10.36
A1	1.22	1.42	E5	7.06	-
A2	2.49	2.89	e	2. 54BSC	
A3	0.00	0. 25	Н	14. 70	15.50
b	0.70	0.96	H2	1.07	1.47
b1	1.17	1.47	L	2.00	2.60
с	0.30	0.53	L1	1.40	1.70
D1	8.50	8.90	L4	0. 25BSC	
D4	6. 60	-	θ	0°	9°

V3.0

E



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